

## Objective and Scope

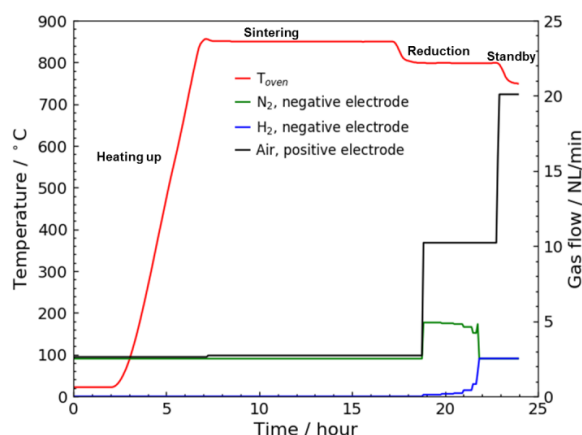
This test module deals with the start-up procedure of solid oxide cells/stacks needed to achieve operating conditions. Start-up includes the heating step and if needed, the gas tightness and electrical contact optimization, the reduction and the conditioning of the SOC stack or cell. The start-up procedure should be given by the manufacturer. However, if there is no start-up procedure available, a recommendation is given in this test module.

## Main Test Input Parameters (TIPs)

| Static TIP   | Variable TIP                                  |
|--|---|
| Rate of oven temperature change ( $\Delta T_{oven}/\Delta t$ ) | Temperature of the oven ( $T_{oven}$ )        |
|  | Temperature of the pre-heater ( $T_{PH,in}$ ) |
|  | Flow rates of inlet gases ( $f_{in}$ )        |
|  | Composition of inlet gases ( $X_{i,in}$ )     |

## Test Procedure

- Set the flow for the negative ( $f_{neg,in}$ ) electrode to N<sub>2</sub> or Ar. Set the flow for the positive electrode ( $f_{pos,in}$ ) to air.
- Increase cell/stack temperature by setting  $T_{oven}$  to the required sealing temperature. Increase the gas inlet temperatures (if possible) by adjusting  $T_{PH,in}$ .
- Hold time at sealing temperature according to setup requirements.
- Change  $T_{oven}$  to the reduction temperature required by the SOCs. Initiate the reduction process (e.g. by increasing H<sub>2</sub> flow stepwise).
- Change  $T_{oven}$  to the operating temperature; change the reactants to nominal operation flow/composition.



Schematic example of start-up procedure for non-reduced SOC cell/stack

## Critical Parameters and Parameter Controls

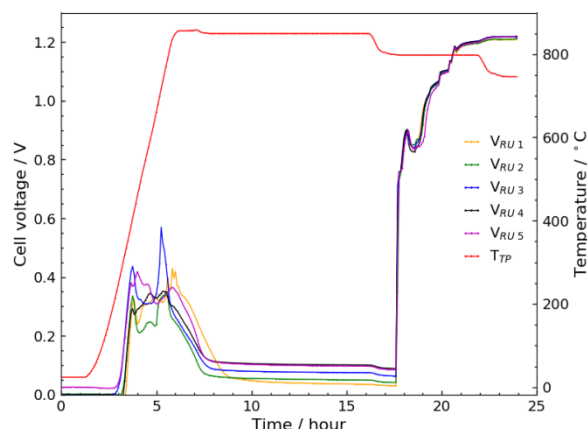
- A large temperature gradient between the gas inlets and the cell/stack should be avoided to reduce the risk of cell/stack damage

## Main Test Output Parameters (TOPs) and Derived Quantities

| TOP  | Derived Quantities  |
|--|---|
| Voltage of cell/stack (V)  | Maximum temperature difference during start-up ( $\Delta T_{max}$ ) |
| Temperature of gas streams at cell/stack inlet/outlet, temperature of cell/stack (T) |   |

## Data Post Processing and Representation

Representation examples of start-up:



Schematic example of startup procedure for non-reduced 5-cells SOC stack

